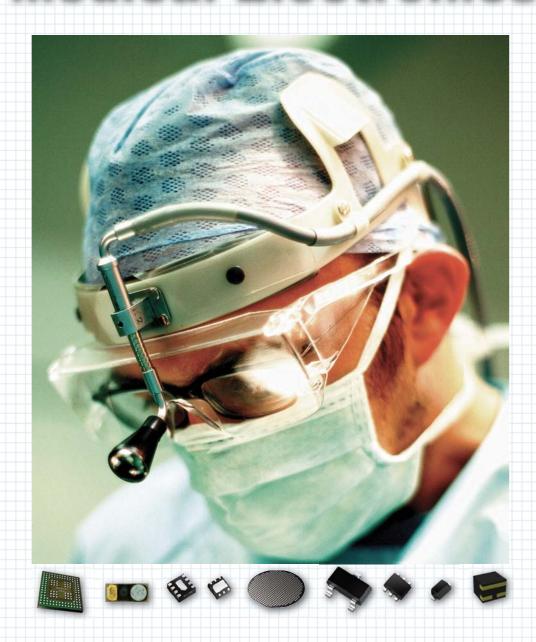
# Implantable Medical Electronics





### Heritage of Reliability

From its start a half century ago, Microsemi has focused on supplying devices of highest reliability, initially for mission-critical defense and aerospace applications. Drawing upon this expertise, Microsemi has spent more than 30 years serving and investing in the unique requirements of implantable medical technology. It's an unmatched commitment and a mark of our leadership.

- More than 30 years experience supporting implantable device designs
- Proven reliability through 100's of millions of hours protecting patients
- Consistent investment in innovative performance enhancements.
- Innovative packaging with extensive product customization capabilities
- MIL/ISO/AS qualified production facilities

Throughout our history as a leading supplier of circuit protection and power management semiconductors and modules, Microsemi has developed close relationships that allow us to create customized solutions supporting customer innovations and new product developments. We understand your unique design and safety requirements.

Simultaneously, Microsemi embraces a conservative product obsolescence policy that provides long product lifetimes, ensuring a reliable continuity of supply.

Our medical protection portfolio includes
Schottky diodes, Zener diodes, high voltage
diodes, transient voltage suppressors, thyristor
surge protection devices, IGBTs and MOSFETs.
Our solutions include bare die, arrays of die
and a broad range of discrete and integrated
packaged parts.

### Microsemi Implantable Technologies

#### Zener Diodes

- Temperature compensated ultra-stable reference diodes
- High surge current capability
- · Low reverse leakage
- 2V to 200V

### **High Voltage Rectifiers**

- · Soft recovery ultra fast diodes
- 200V to 1200V

#### **MOSFETs**

- · Fast switching or low RDS(ON)
- 100V to 1200V
- Up to 100A
- Fast switching 20KHz to 1MHz
- Low RDS(ON)

#### **IGBTs**

- 300V to 1200V
- Up to 150A
- 20KHz to 200KHz

### **Protection Devices**

Transient Voltage Suppression (TVS)

- Ultra low capacitance < 3 pF for fast response time
- Unidirectional and bidirectional devices
- Low voltage protection, from 1 to 400 volts

### TVS Protection Array Packaging

- µBGA/µDFN
- PSOI™
- STRAP

### Thyristors/SCR/RGT

200V to 1600V

### **Power Conditioning**

Schottky Diodes

- · Low Vf, fastest switching
- 5V to 200V

#### **Transistors**

· Bipolar small signal

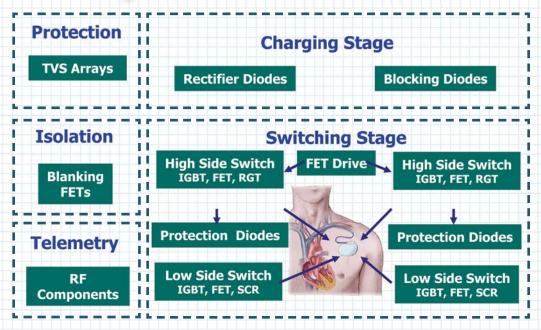
#### RF/Telemetry

Pin Diodes

Varactor Diodes

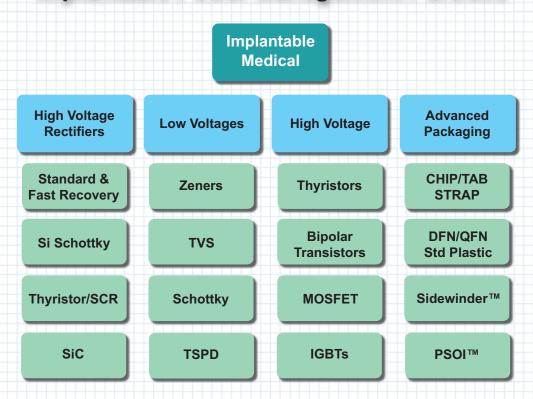
RF MOSFETs

### Implantable Cardio Defibrillator



Optimized solutions for your charging, switching and protecting requirements.

### Implantable Power Management Portfolio



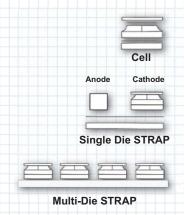
A comprehensive portfolio for all your power management needs.

### Advanced Packaging

Microsemi offers a full range of packaging options to satisfy the needs of Hi-Rel application designs. Included are die and flip chip, µDFN/QFN, µBGAs, arrays, STRAPs and cell, tabs disc-diedisc, Power Silicon on Insulator (PSOI)™, and standard plastic surface mounts. Our packaging is RoHS compliant, with tin/lead finishes also available.

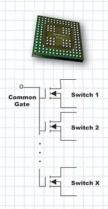
### Cells and STRAPs

- CELL adds molybdenum discs to die to provide mechanical protection
- STRAP brings Anode "up" using tungsten strap to eliminate wire bonds
- Reduces footprint by 20% over chip and wire



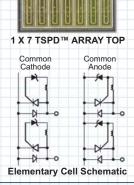
### High Voltage μBGA

- · Industry standard pitches
- · Industry standard ball heights
- · Ease of assembly, stacking and inspection
- · Custom sizes and layouts are available



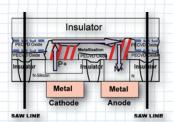
### Flip Chip TVS Arrays Thyristor Surge Protection Device (TSPD™)

- · Monolithic surge protection
- Provides ~ 50 percent size reduction compared to ship and wire while maintaining surge performance
- Available with wire bondable or solderable contacts
- Applicable to low voltage only



### PSOI™—Power Silicon on Insulator

- Stronger and easier to handle than conventional flip chip designs
- Stackable for 3D
- · Excellent thermal characteristics
- Excellent surge characteristics
- Available in Zener, TVS, Schottky, and FRR configurations



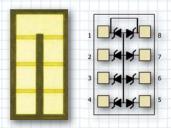
### High Voltage Sidewinder™

- · Turns HV die on edge
- Smallest footprint for a given rating
- 72 percent footprint reduction over an equivalent chip and wire
- · Maintains safe spacing for high voltages
- · No wire bonding required



### **PSOI™ TVS Arrays**

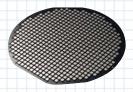
- Reduces footprint while maintaining surge performance
- · Eliminates cross talk
  - Complete isolation by design
- No wire bonds
  - Enhanced device reliability
  - Reduces parasitic inductance and capacitance



2 x 4 PSOI Array Top Looking through Glass Insulator

### Die and Wafers

- · Provides 100% Electrical Screening
- Provides 100% Visual Inspection
- Package Burn-in
- Lot Acceptance Testing (LAT)
- Wafer-level Traceability and Documentation
- Custom die designs
- WafflePack, Tape & Reel, or Sawn on Frames



Silicon Wafer



Silicon Carbide

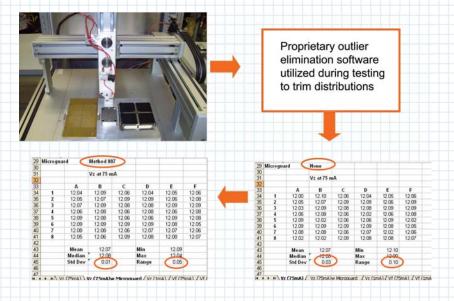
### Standard Packages Available



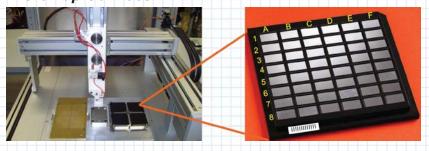
### Value Added Services

Microsemi Hi-Rel products undergo extensive electrical, visual, burn-in and LAT/WAT screening. Manufacturing processes to include our exclusive Microvalidation reports, Micromap™ and Microguard™ services. We offer wafer/die bank services, as well as buffer stock inventory management.

### **Microguard Services**



### Micromap Services

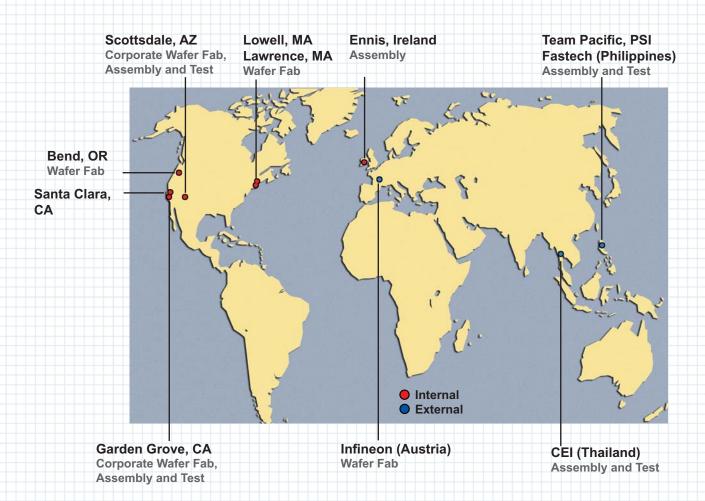


- Serialized testing via bar code
- Waffle pack Micromap of parametric data
- Enables individual component traceability w/o additional test OH
- · Facilitates customer CIM strategies
- · Web accessible parametric data
- · Now in development

31		Vz at 75 mA					
12							
33		A	В	C	D	E	F
14	1	12.00	12.10	12.06	12.04	12.05	12.06
5	2	12.05	12.07	12.09	12.09	12.06	12.09
6	3	12.03	12.09	12.08	12.08	12.09	12.09
37	4	12.06	12.08	12.06	12.02	12.06	12.08
38	5	12.09	12.02	12.06	12.06	12.09	12.02
19	6	12.09	12.09	12.09	12.09	12.08	12.05
0	7	12.08	12.08	12.06	12.07	12.02	12.06
11	8	12.02	12.02	12.09	12.08	12.08	12.07
2							
13		Mean	12.07		Min	12.10	
14		Median	12.08		Maox	12.00	
5		Std Dev	0.03		Range	0.10	
6					2000		
7		(75ma) /					

### **Global Manufacturing**

Most die are manufactured at our wafer fabrication facilities in the United States. Our Microsemi Scottsdale, AZ facility is your focal point for implantable medical products. Standard plastic packaging is available from in-house and contract manufacturers.



## One-Stop Coordination For Medical Applications

Microsemi has a team of specialists available to provide innovative solutions for your implantable medical requirements.

Call for more information and to discuss your specific needs.

Microsemi Corporation
Implantable Medical Products
8700 East Thomas Road
Scottsdale, AZ 85252

Specialist Direct: (480) 941-6536

Sales Direct: (602) 320-5916

Fax: (480) 947-1503

